Hex buffer/line driver; 3-state; inverting Rev. 5 — 2 February 2016

#### **General description** 1.

The 74HC366; 74HCT366 is a hex inverting buffer/line driver with 3-state outputs controlled by the output enable inputs (OEn). A HIGH on OEn causes the outputs to assume a high impedance OFF-state. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V<sub>CC</sub>.

#### **Features and benefits** 2.

- Inverting outputs
- Input levels:
  - For 74HC366: CMOS level
  - For 74HC366: TTL level
- Complies with JEDEC standard no. 7A
- ESD protection:
  - HBM JESD22-A114F exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V
- Specified from –40 °C to +85 °C and from –40 °C to +125 °C
- Multiple package options

#### **Ordering information** 3.

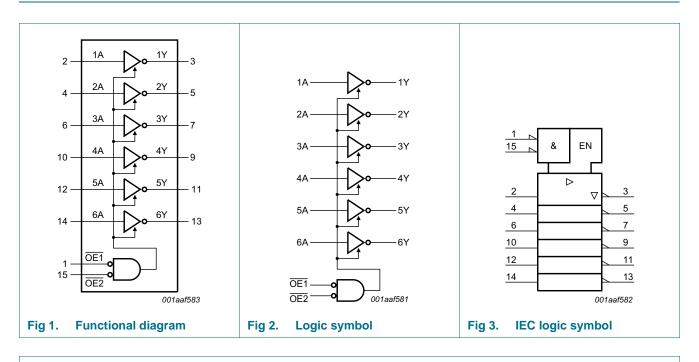
#### Table 1. **Ordering information**

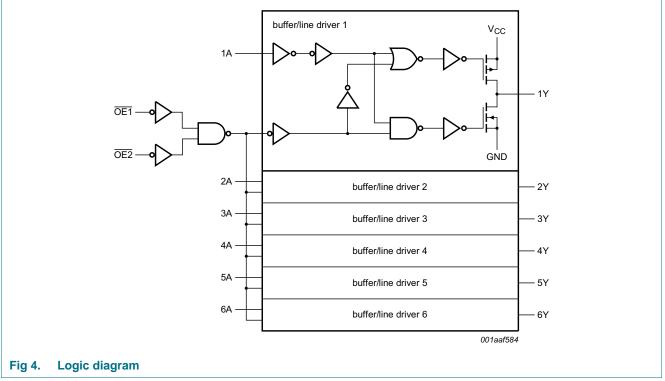
Type number	Package			
	Temperature range	Name	Description	Version
74HC366				
74HC366D	–40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1
74HC366PW	–40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1
74HCT366				
74HCT366D	–40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1
74HCT366DB	–40 °C to +125 °C	SSOP16	plastic shrink small outline package; 16 leads; body width 5.3 mm	SOT338-1
74HCT366PW	−40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1

# nexperia

Hex buffer/line driver; 3-state; inverting

### 4. Functional diagram



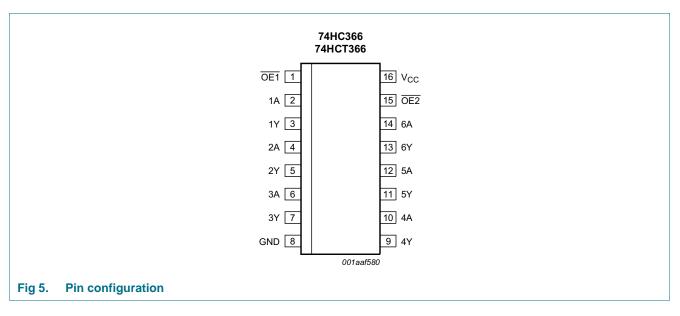


**Product data sheet** 

Hex buffer/line driver; 3-state; inverting

### 5. Pinning information

### 5.1 Pinning



### 5.2 Pin description

#### Table 2. Pin description

Symbol	Pin	Description
OE1, OE2	1, 15	output enable input (active LOW)
1A, 2A, 3A, 4A, 5A, 6A	2, 4, 6, 10, 12, 14	data input
1Y, 2Y, 3Y, 4Y, 5Y, 6Y	3, 5, 7, 9, 11, 13	data output
GND	8	ground (0 V)
V <sub>CC</sub>	16	supply voltage

## 6. Functional description

#### Table 3. Function table<sup>[1]</sup>

		Input	Output
OE1	OE2	nA	nY
L	L	L	Н
L	L	Н	L
Х	Н	Х	Z
Н	Х	Х	Z

[1] H = HIGH voltage level;

L = LOW voltage level;

X = don't care;

Z = high-impedance OFF-state.

Hex buffer/line driver; 3-state; inverting

### 7. Limiting values

#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+7	V
I <sub>IK</sub>	input clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$	-	±20	mA
I <sub>OK</sub>	output clamping current	$V_{\rm O}$ < -0.5 V or $V_{\rm O}$ > $V_{\rm CC}$ + 0.5 V	-	±20	mA
lo	output current	$V_{O} = -0.5 \text{ V to} (V_{CC} + 0.5 \text{ V})$	-	±35	mA
I <sub>CC</sub>	supply current		-	70	mA
I <sub>GND</sub>	ground current		-	-70	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	SO16 package	-	500	mW
		SSOP16 package [2]	-	500	mW
		TSSOP16 package [2]	-	500	mW

[1] For SO16 packages:  $P_{tot}$  derates linearly with 8 mW/K above 70 °C.

[2] For SSOP16 and TSSOP16 packages:  $P_{tot}$  derates linearly with 5.5 mW/K above 60 °C.

### 8. Recommended operating conditions

#### Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions		74HC366	5	7	4HCT36	6	Unit
			Min	Тур	Max	Min	Тур	Max	
V <sub>CC</sub>	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V <sub>CC</sub>	0	-	V <sub>CC</sub>	V
Vo	output voltage		0	-	V <sub>CC</sub>	0	-	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		-40	+25	+125	-40	+25	+125	°C
Δt/ΔV	input transition rise and fall rate	$V_{CC} = 2.0 V$	-	-	625	-	-	-	ns/V
		$V_{CC} = 4.5 V$	-	1.67	139	-	1.67	139	ns/V
		$V_{CC} = 6.0 V$	-	-	83	-	-	-	ns/V

Hex buffer/line driver; 3-state; inverting

## 9. Static characteristics

#### Table 6. Static characteristics 74HC366

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

T <sub>amb</sub> = 2 V <sub>IH</sub>	25 °C HIGH-level input voltage					
V <sub>IH</sub>	HIGH-level input voltage					
	i iiGi i-level iliput voltage	V <sub>CC</sub> = 2.0 V	1.5	1.2	-	V
		V <sub>CC</sub> = 4.5 V	3.15	2.4	-	V
		V <sub>CC</sub> = 6.0 V	4.2	3.2	-	V
VIL	LOW-level input voltage	V <sub>CC</sub> = 2.0 V	-	0.8	0.5	V
		V <sub>CC</sub> = 4.5 V	-	2.1	1.35	V
		V <sub>CC</sub> = 6.0 V	-	2.8	1.8	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>	-	-	-	
		$I_0 = -20 \ \mu\text{A}; \ V_{CC} = 2.0 \ \text{V}$	1.9	2.0	-	V
		$I_{O} = -20 \ \mu\text{A}; \ V_{CC} = 4.5 \ \text{V}$	4.4	4.5	- 0.5 1.35 1.8 - - - - - - - - - - - - -	V
		$I_0 = -20 \ \mu\text{A}; \ V_{CC} = 6.0 \ \text{V}$	5.9	6.0		V
		$I_{O} = -6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.98	4.32	-	V
		$I_{O} = -7.8 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.48	5.81	-	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		$I_0 = 20 \ \mu A; \ V_{CC} = 2.0 \ V$	-	0	0.1	V
		$I_0 = 20 \ \mu A; V_{CC} = 4.5 \ V$	-	0	0.1	V
		$I_0 = 20 \ \mu A; V_{CC} = 6.0 \ V$	-	0 0.4	0.1	V
		$I_{O} = 6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	0.15	0.26	V
		I <sub>O</sub> = 7.8 mA; V <sub>CC</sub> = 6.0 V	-	0.16	0.26	V
l <sub>l</sub>	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 V$	-	-	±0.1	μA
l <sub>oz</sub>	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{O} = V_{CC} \text{ or } \text{GND}; V_{CC} = 6.0 \text{ V}$	-	-	±0.5	μA
I <sub>CC</sub>	supply current	$V_{I} = V_{CC}$ or GND; $I_{O} = 0$ A; $V_{CC} = 6.0$ V	-	-	8.0	μA
CI	input capacitance		-	3.5	-	pF
T <sub>amb</sub> = -	-40 °C to +85 °C	1				
VIH	HIGH-level input voltage	V <sub>CC</sub> = 2.0 V	1.5	-	-	V
		V <sub>CC</sub> = 4.5 V	3.15	-	-	V
		V <sub>CC</sub> = 6.0 V	4.2	-	-	V
VIL	LOW-level input voltage	V <sub>CC</sub> = 2.0 V	-	-	1.35 1.8 - - - - - - 0.1 0.1 0.1 0.26 0.26 ±0.1 ±0.5 8.0 - - - - - - - - - - - - -	V
		V <sub>CC</sub> = 4.5 V	-	-		V
		V <sub>CC</sub> = 6.0 V	-	-	1.8	V
V <sub>OH</sub>	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_0 = -20 \ \mu A; \ V_{CC} = 2.0 \ V$	1.9	-	-	V
		$I_0 = -20 \ \mu A; \ V_{CC} = 4.5 \ V$	4.4	-	-	V
		$I_{O} = -20 \ \mu A; \ V_{CC} = 6.0 \ V$	5.9	-	-	V
		$I_{O} = -6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.84	-	-	V
		I <sub>O</sub> = -7.8 mA; V <sub>CC</sub> = 6.0 V	5.34	-	-	V

Hex buffer/line driver; 3-state; inverting

#### Table 6. Static characteristics 74HC366 ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		$I_0 = 20 \ \mu A; \ V_{CC} = 2.0 \ V$	-	-	0.1	V
		$I_{O} = 20 \ \mu A; \ V_{CC} = 4.5 \ V$	-	-	0.1	V
		$I_0 = 20 \ \mu A; \ V_{CC} = 6.0 \ V$	-	-	0.1	V
		$I_{O} = 6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.33	V
		I <sub>O</sub> = 7.8 mA; V <sub>CC</sub> = 6.0 V	-	-	0.33	V
l <sub>l</sub>	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0$ V;	-	-	±1.0	μA
l <sub>oz</sub>	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{O} = V_{CC} \text{ or } \text{GND}; V_{CC} = 6.0 \text{ V}$	-	-	±5.0	μA
I <sub>CC</sub>	supply current	$V_{I} = V_{CC}$ or GND; $I_{O} = 0$ A; $V_{CC} = 6.0$ V	-	-	80	μA
T <sub>amb</sub> = -	40 °C to +125 °C	·				<u>.</u>
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 2.0 V	1.5	-	-	V
		V <sub>CC</sub> = 4.5 V	3.15	-	-	V
		V <sub>CC</sub> = 6.0 V	4.2	-	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 2.0 V	-	-	0.5	V
		V <sub>CC</sub> = 4.5 V	-	-	1.35	V
		V <sub>CC</sub> = 6.0 V	-	-	1.8	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		$I_0 = -20 \ \mu\text{A}; \ V_{CC} = 2.0 \ \text{V}$	1.9	-	-	V
		$I_0 = -20 \ \mu\text{A}; \ V_{CC} = 4.5 \ \text{V}$	4.4	-	-	V
		$I_0 = -20 \ \mu\text{A}; \ V_{CC} = 6.0 \ \text{V}$	5.9	-	-	V
		$I_{O} = -6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.7	-	-	V
		$I_0 = -7.8 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.2	-	-	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		$I_0 = 20 \ \mu A; \ V_{CC} = 2.0 \ V$	-	-	0.1	V
		$I_{O} = 20 \ \mu A; \ V_{CC} = 4.5 \ V$	-	-	0.1	V
		$I_0 = 20 \ \mu A; \ V_{CC} = 6.0 \ V$	-	-	0.1	V
		I <sub>O</sub> = 6.0 mA; V <sub>CC</sub> = 4.5 V	-	-	0.4	V
		$I_0 = 7.8 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	-	0.4	V
l <sub>l</sub>	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±1.0	μA
I <sub>OZ</sub>	OFF-state output current	$V_{I} = V_{IH}$ or $V_{IL}$ ; $V_{O} = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±10.0	μA
I <sub>CC</sub>	supply current	$V_{I} = V_{CC}$ or GND; $I_{O} = 0$ A; $V_{CC} = 6.0$ V	-	-	160	μA

Hex buffer/line driver; 3-state; inverting

#### Table 7. Static characteristics 74HCT366

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = 2	25 °C					_
VIH	HIGH-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	2.0	1.6	-	V
VIL	LOW-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	-	1.2	0.8	V
V <sub>OH</sub>	HIGH-level output	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$				
	voltage	I <sub>O</sub> = -20 μA	4.4	4.5	-	V
		I <sub>O</sub> = -6.0 mA	3.98	4.32	-	V
V <sub>OL</sub>	LOW-level output	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$				
	voltage	I <sub>O</sub> = 20 μA	-	0	0.1	V
		I <sub>O</sub> = 6.0 mA	-	0.16	0.26	V
l <sub>l</sub>	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 V$	-	-	±0.1	μA
l <sub>oz</sub>	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{O} = V_{CC} \text{ or GND}; V_{CC} = 5.5 \text{ V}$	-	-	±0.5	μA
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V	-	-	8.0	μA
$\Delta I_{CC}$	additional supply current	$V_I = V_{CC} - 2.1$ V; other inputs at $V_{CC}$ or GND; $I_O = 0$ A				
		pins nA	-	100	360	μA
		pin OE1	-	100	360	μA
		pin OE2	-	90	320	μA
CI	input capacitance		-	3.5	-	pF
T <sub>amb</sub> = -	-40 °C to +85 °C					_
VIH	HIGH-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	2.0	-	-	V
V <sub>IL</sub>	LOW-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	-	-	0.8	V
V <sub>OH</sub>	HIGH-level output	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$				
	voltage	I <sub>O</sub> = -20 μA	4.4	-	-	V
		I <sub>O</sub> = -6.0 mA	3.84	-	-	V
V <sub>OL</sub>	LOW-level output	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$				
	voltage	I <sub>O</sub> = 20 μA	-	-	0.1	V
		I <sub>O</sub> = 6.0 mA	-	-	0.33	V
l <sub>l</sub>	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 V$	-	-	±1.0	μA
l <sub>oz</sub>	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{O} = V_{CC} \text{ or GND}; V_{CC} = 5.5 \text{ V}$			±5.0	μA
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V	-	-	80	μA
$\Delta I_{CC}$	additional supply current	$V_I = V_{CC} - 2.1$ V; other inputs at $V_{CC}$ or GND; $I_O = 0$ A				
		pins nA	-	-	450	μA
		pin OE1	-	-	450	μA
		pin OE2	-	-	400	μA

Hex buffer/line driver; 3-state; inverting

#### Table 7. Static characteristics 74HCT366 ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = -	40 °C to +125 °C					
V <sub>IH</sub>	HIGH-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	2.0	-	-	V
V <sub>IL</sub>	LOW-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	-	-	0.8	V
V <sub>OH</sub>	HIGH-level output	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$				
	voltage	I <sub>O</sub> = -20 μA	4.4	-	-	V
		$I_{\rm O} = -6.0  \rm{mA}$	3.7	-	-	V
V <sub>OL</sub>	LOW-level output	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$				
	voltage	I <sub>O</sub> = 20 μA	-	-	0.1	V
		I <sub>O</sub> = 6.0 mA	-	-	0.4	V
I <sub>I</sub>	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 5.5 V$	-	-	±1.0	μA
I <sub>OZ</sub>	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{O} = V_{CC} \text{ or GND}; V_{CC} = 5.5 \text{ V}$	-	-	±10.0	μA
I <sub>CC</sub>	supply current	$V_{I} = V_{CC}$ or GND; $I_{O} = 0$ A; $V_{CC} = 5.5$ V	-	-	160	μA
$\Delta I_{CC}$	additional supply current	$V_I = V_{CC} - 2.1$ V; other inputs at $V_{CC}$ or GND; $I_O = 0$ A				
		pins nA	-	-	490	μA
		pin OE1	-	-	490	μA
		pin OE2	-	-	441	μA

### **10.** Dynamic characteristics

#### Table 8. Dynamic characteristics 74HC366

Voltages are referenced to GND (ground = 0 V);  $C_L = 50 \text{ pF}$  unless otherwise specified; see test circuit Figure 8.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
T <sub>amb</sub> = 2	5 °C			1	•	1	-1
t <sub>pd</sub>	propagation delay	nA to nY; see Figure 6	<u>[1]</u>				
		V <sub>CC</sub> = 2.0 V		-	33	100	ns
		V <sub>CC</sub> = 4.5 V		-	12	20	ns
		V <sub>CC</sub> = 5 V; C <sub>L</sub> = 15 pF		-	10	-	ns
		V <sub>CC</sub> = 6.0 V		-	10	17	ns
t <sub>en</sub>	enable time	OEn to nY; see Figure 7	[2]				
		V <sub>CC</sub> = 2.0 V		-	44	150	ns
		V <sub>CC</sub> = 4.5 V		-	16	30	ns
		V <sub>CC</sub> = 6.0 V		-	13	26	ns
t <sub>dis</sub>	disable time	OEn to nY; see Figure 7	[3]				
		V <sub>CC</sub> = 2.0 V		-	55	150	ns
		V <sub>CC</sub> = 4.5 V		-	20	30	ns
		V <sub>CC</sub> = 6.0 V		-	16	26	ns
t <sub>t</sub>	transition time	see <u>Figure 6</u>	<u>[4]</u>				
		V <sub>CC</sub> = 2.0 V		-	14	60	ns
		V <sub>CC</sub> = 4.5 V		-	5	12	ns
		V <sub>CC</sub> = 6.0 V		-	4	10	ns

Hex buffer/line driver; 3-state; inverting

#### Table 8. Dynamic characteristics 74HC366 ...continued

Voltages are referenced to GND (ground = 0 V);  $C_L = 50 \text{ pF}$  unless otherwise specified; see test circuit Figure 8.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
C <sub>PD</sub>	power dissipation capacitance	per buffer; $V_I = GND$ to $V_{CC}$	[5]	-	30	-	pF
T <sub>amb</sub> = -	40 °C to +85 °C	'					_
t <sub>pd</sub>	propagation delay	nA to nY; see Figure 6	<u>[1]</u>				
		V <sub>CC</sub> = 2.0 V		-	-	125	ns
		V <sub>CC</sub> = 4.5 V		-	-	25	ns
		V <sub>CC</sub> = 6.0 V		-	-	21	ns
t <sub>en</sub>	enable time	OEn to nY; see Figure 7	[2]				
		V <sub>CC</sub> = 2.0 V		-	-	190	ns
		V <sub>CC</sub> = 4.5 V		-	-	38 33 190 38 33	ns
		V <sub>CC</sub> = 6.0 V		-	-		ns
t <sub>dis</sub>	disable time	OEn to nY; see Figure 7	[3]				
		V <sub>CC</sub> = 2.0 V		-	-	190	ns
		V <sub>CC</sub> = 4.5 V		-	-	38	ns
		V <sub>CC</sub> = 6.0 V		-	-	33	ns
t <sub>t</sub>	transition time	see <u>Figure 6</u>	<u>[4]</u>			75	
		V <sub>CC</sub> = 2.0 V		-	-		ns
		V <sub>CC</sub> = 4.5 V		-	-	15	ns
		V <sub>CC</sub> = 6.0 V		-	-	13	ns
T <sub>amb</sub> = -	40 °C to +125 °C						_
t <sub>pd</sub>	propagation delay	nA to nY; see <u>Figure 6</u>	<u>[1]</u>				
		V <sub>CC</sub> = 2.0 V		-	-	150	ns
		V <sub>CC</sub> = 4.5 V		-	-	30	ns
		V <sub>CC</sub> = 6.0 V		-	-	26	ns
t <sub>en</sub>	enable time	OEn to nY; see Figure 7	[2]				
		V <sub>CC</sub> = 2.0 V		-	-	225	ns
		V <sub>CC</sub> = 4.5 V		-	-	45	ns
		V <sub>CC</sub> = 6.0 V		-	-	38	ns
t <sub>dis</sub>	disable time	OEn to nY; see Figure 7	[3]				
		V <sub>CC</sub> = 2.0 V		-	-	225	ns
		V <sub>CC</sub> = 4.5 V		-	-	45	ns
		$V_{CC} = 6.0 V$		-	-	38	ns

#### Hex buffer/line driver; 3-state; inverting

#### Table 8. Dynamic characteristics 74HC366 ...continued

Voltages are referenced to GND (ground = 0 V);  $C_L = 50 \text{ pF}$  unless otherwise specified; see test circuit Figure 8.

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
t <sub>t</sub>	transition time	see Figure 6 [4]				
		$V_{CC} = 2.0 V$	-	-	90	ns
		$V_{CC} = 4.5 V$	-	-	18	ns
		$V_{CC} = 6.0 V$	-	-	15	ns

[1]  $t_{pd}$  is the same as  $t_{PHL}$  and  $t_{PLH}$ .

[2]  $t_{en}$  is the same as  $t_{PZH}$  and  $t_{PZL}$ .

[3]  $t_{dis}$  is the same as  $t_{PHZ}$  and  $t_{PLZ}$ .

[4]  $t_t$  is the same as  $t_{THL}$  and  $t_{TLH}$ .

[5]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ).

 $P_{D} = C_{PD} \times V_{CC}^{2} \times f_{i} \times N + \sum (C_{L} \times V_{CC}^{2} \times f_{o}) \text{ where:}$ 

 $f_i = input frequency in MHz;$ 

 $f_o$  = output frequency in MHz;

 $C_L$  = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of outputs.

#### Table 9. Dynamic characteristics 74HCT366

Voltages are referenced to GND (ground = 0 V);  $C_L = 50 \text{ pF}$  unless otherwise specified; see test circuit Figure 8.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
T <sub>amb</sub> = 2	5 °C						-
t <sub>pd</sub>	propagation delay	nA to nY; see Figure 6					
		$V_{CC} = 4.5 V$		-	13	24	ns
		$V_{CC} = 5 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$		-	11	-	ns
t <sub>en</sub>	enable time	$\overline{\text{OEn}}$ to nY; V <sub>CC</sub> = 4.5 V; see Figure 7	[2]	-	16	35	ns
t <sub>dis</sub>	disable time	$\overline{\text{OEn}}$ to nY; V <sub>CC</sub> = 4.5 V; see Figure 7 [3]		-	20	35	ns
tt	transition time	V <sub>CC</sub> = 4.5 V; see <u>Figure 6</u>	<u>[4]</u>	-	5	12	ns
C <sub>PD</sub>	power dissipation capacitance	per buffer; $V_I = GND$ to $(V_{CC} - 1.5 V)$	<u>[5]</u>	-	30	-	pF
T <sub>amb</sub> = -	40 °C to +85 °C					1	
t <sub>pd</sub>	propagation delay	nA to nY; $V_{CC}$ = 4.5 V; see <u>Figure 6</u>	<u>[1]</u>	-	-	30	ns
t <sub>en</sub>	enable time	$\overline{\text{OEn}}$ to nY; V <sub>CC</sub> = 4.5 V; see Figure 7	[2]	-	-	44	ns
t <sub>dis</sub>	disable time	$\overline{\text{OEn}}$ to nY; V <sub>CC</sub> = 4.5 V; see Figure 7	<u>[3]</u>	-	-	44	ns
t <sub>t</sub>	transition time	$V_{CC}$ = 4.5 V; see Figure 6	<u>[4]</u>	-	-	15	ns

#### Hex buffer/line driver; 3-state; inverting

#### Table 9. Dynamic characteristics 74HCT366 ...continued

Voltages are referenced to GND (ground = 0 V);  $C_L = 50 \text{ pF}$  unless otherwise specified; see test circuit Figure 8.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
•	l0 °C to +125 °C	I		,		
t <sub>pd</sub>	propagation delay	nA to nY; $V_{CC}$ = 4.5 V; see Figure 6 [1]	-	-	36	ns
t <sub>en</sub>	enable time	$\overline{\text{OEn}}$ to nY; V <sub>CC</sub> = 4.5 V; see Figure 7 [2]	-	-	53	ns
t <sub>dis</sub>	disable time	$\overline{\text{OEn}}$ to nY; V <sub>CC</sub> = 4.5 V; see Figure 7 [3]	-	-	53	ns
t <sub>t</sub>	transition time	V <sub>CC</sub> = 4.5 V; see <u>Figure 6</u> [4]	-	-	18	ns

[1]  $t_{pd}$  is the same as  $t_{PHL}$  and  $t_{PLH}$ .

[2]  $t_{en}$  is the same as  $t_{PZH}$  and  $t_{PZL}$ .

[3]  $t_{dis}$  is the same as  $t_{PHZ}$  and  $t_{PLZ}$ .

 $\label{eq:ttime_time} [4] \quad t_t \text{ is the same as } t_{THL} \text{ and } t_{TLH}.$ 

[5]  $C_{PD}$  is used to determine the dynamic power dissipation (P<sub>D</sub> in  $\mu$ W).

 $P_{D} = C_{PD} \times V_{CC}^{2} \times f_{i} \times N + \sum (C_{L} \times V_{CC}^{2} \times f_{o}) \text{ where:}$ 

 $f_i = input frequency in MHz;$ 

 $f_o = output frequency in MHz;$ 

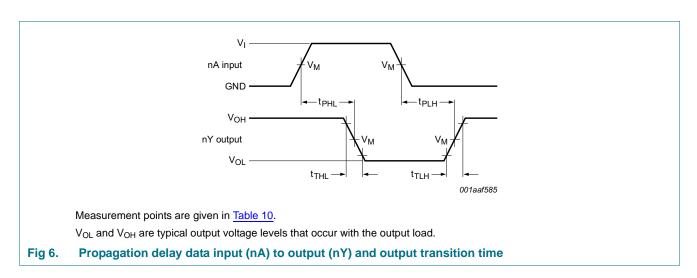
 $C_L$  = output load capacitance in pF;

 $V_{CC}$  = supply voltage in V;

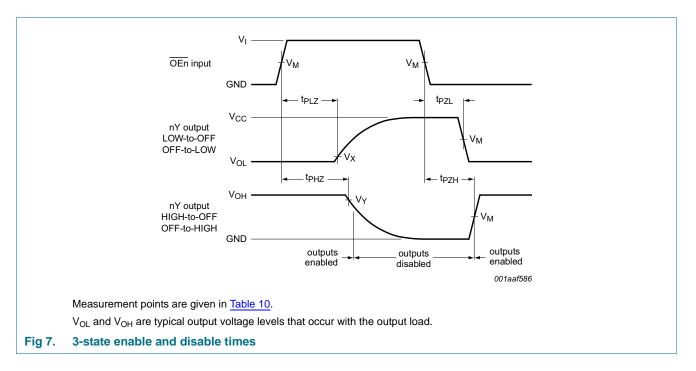
N = number of inputs switching;

 $\sum (C_L \times V_{CC}^2 \times f_o) =$ sum of outputs.

### 11. Waveforms



Hex buffer/line driver; 3-state; inverting

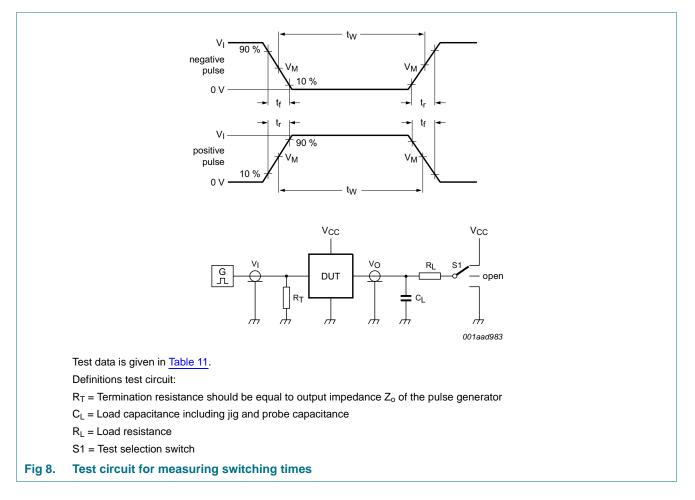


#### Table 10. Measurement points

Туре	Input	Output		
	V <sub>M</sub>	V <sub>M</sub>	V <sub>X</sub>	V <sub>Y</sub>
74HC366	0.5V <sub>CC</sub>	0.5V <sub>CC</sub>	$0.1 \times V_{CC}$	$0.9 \times V_{CC}$
74HCT366	1.3 V	1.3 V	$0.1 \times V_{CC}$	$0.9 \times V_{CC}$

74HC\_HCT366

#### Hex buffer/line driver; 3-state; inverting

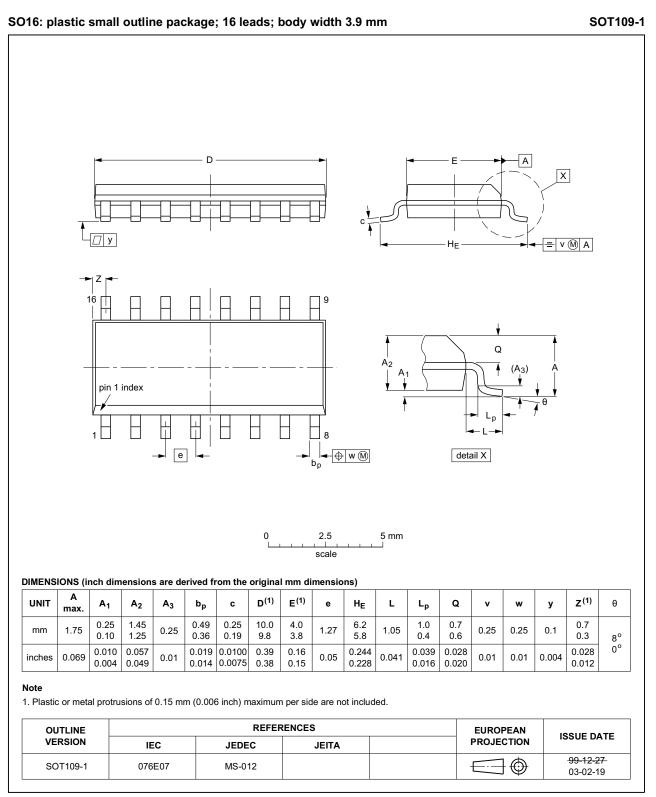


#### Table 11. Test data

Туре	Input		Load		S1 position		
	VI	t <sub>r</sub> , t <sub>f</sub>	CL	RL	t <sub>PHL</sub> , t <sub>PLH</sub>	t <sub>PZH</sub> , t <sub>PHZ</sub>	t <sub>PZL</sub> , t <sub>PLZ</sub>
74HC366	V <sub>CC</sub>	6 ns	15 pF, 50 pF	1 kΩ	open	GND	V <sub>CC</sub>
74HCT366	3 V	6 ns	15 pF, 50 pF	1 kΩ	open	GND	V <sub>CC</sub>

Hex buffer/line driver; 3-state; inverting

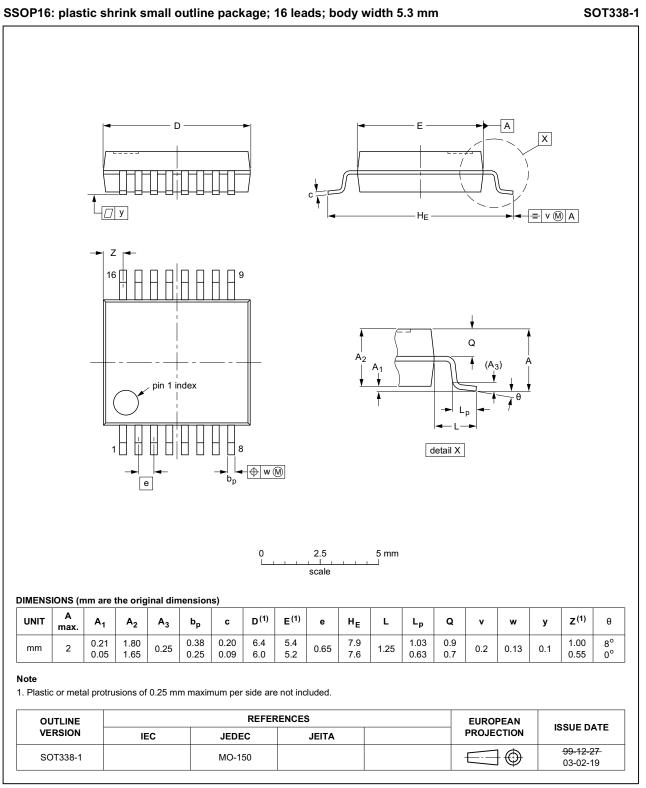
### 12. Package outline



#### Fig 9. Package outline SOT109-1 (SO16)

74HC\_HCT366

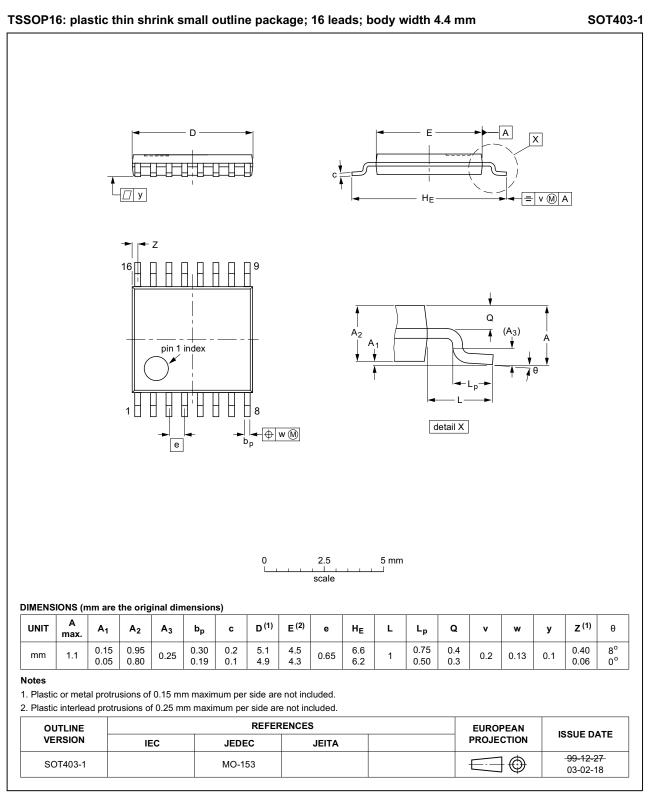
Hex buffer/line driver; 3-state; inverting



#### Fig 10. Package outline SOT338-1 (SSOP16)

74HC\_HCT366

Hex buffer/line driver; 3-state; inverting



#### Fig 11. Package outline SOT403-1 (TSSOP16)

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Product data sheet

Hex buffer/line driver; 3-state; inverting

### **13. Abbreviations**

Table 12. Abbreviations					
Acronym	Description				
CMOS	Complementary Metal Oxide Semiconductor				
DUT	Device Under Test				
ESD	ElectroStatic Discharge				
HBM	Human Body Model				
MM	Machine Model				

### 14. Revision history

#### Table 13.Revision history

Document ID Release date Data sheet status		Data sheet status	Change notice	Supersedes
74HC_HCT366 v.5	20160202	Product data sheet	-	74HC_HCT366 v.4
Modifications:	Type numbers	s 74HC366N and 74HCT366N	(SOT38-4) removed	J.
74HC_HCT366 v.4	20120904	Product data sheet	-	74HC_HCT366 v.3
Modifications:	<ul> <li>Legal pages u</li> </ul>	updated.		
74HC_HCT366 v.3	20061121	Product data sheet	-	74HC_HCT366_CNV v.2
74HC_HCT366_CNV v.2	19901201	Product specification	-	-

Hex buffer/line driver; 3-state; inverting

## 15. Legal information

### 15.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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#### Hex buffer/line driver; 3-state; inverting

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